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## ກາຄຸນວກ

						Wavelength= 1.54056
	2 <sub>θ</sub>	Int	h	k	l	
43-0303 (PbO 68.75CaO 31.25)TiO <sub>3</sub>						
Lead Calcium Titanium Oxide						
Rad.: CuK $\alpha$ $\lambda$ : 1.5418 Filter: Graph Monod-sp: Diffractometer	22.044	11	0	0	1	
Cut off: 15.0 Int.: Diffract. I/I <sub>cor.</sub> :	22.854	31	1	0	0	
Ref: Martin, K., McCarthy, G., North Dakota State University, Fargo, North Dakota, USA, ICDD Grant-in-Aid, (1991)	31.955	100	1	0	1	
	32.533	59	1	1	0	
	39.654	38	1	1	1	
	44.949*	6	0	0	2	
	46.683	31	2	0	0	
	51.016*	4	1	0	2	
	52.222*	6	2	0	1	
	52.587*	6	2	1	0	
	56.591	10	1	1	2	
Sys.: Tetragonal S.G.: P4/43 (123)	57.691	31	2	1	1	
a: 3.8885(3) b:	c: 4.0292(8) $\alpha$ :	$\gamma$ :	Z: 1	mp:		
Ref: Ibid.	66.815*	8	2	0	2	
Dx: 6.849 Dm:	SS/FOM <sub>2</sub> = 73(0.0132, 30)	68.174*	6	2	2	
		71.632*	3	2	1	
		72.627*	1	2	2	
		72.946*	1	3	0	
		74.697*	2	1	0	
		77.301*	6	3	0	
		77.592*	7	3	1	
		79.320	<1	1	1	
Peak height intensity. Synthesized, contributed and indexed by E. Goo (University of Southern California, USA) via W. Wong-Ng (NIST). See J. Am. Ceram. Soc., 71, 454 (1988). Broad peaks [I'WLLM of (111) = 0.31% at 3°]. Average relative standard deviation in intensity of the eight strongest reflections for three specimen mounts 1.9%. Perovskite, CaO <sub>3</sub> Ti type. Silicon used as an internal stand. PSC: tP5. Mwt: 251.29. Volume[CD]: 60.92.	81.855*	4	3	1	1	
	85.422*	3	2	2	2	
	88.377	<1	2	0	3	
	89.920	<1	3	0	2	
	91.201	<1	3	2	0	
	92.887*	2	2	1	3	
	94.449*	3	3	1	2	
	95.393*	4	3	2	1	

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						Wavelength= 1.54056
	2 <sub>θ</sub>	Int	h	k	l	
04-0802						
Pt						
Platinum						
Platinum, syn						
Rad.: CuK $\alpha$ $\lambda$ : 1.5405 Filter: Ni Beta $\square$ M d-sp:	39.762	100	1	1	1	
Cut off: Int.: Diffract. I/I <sub>cor.</sub> :	46.243	53	2	0	0	
Ref: Swanson, Tate, Natl. Bur. Stand. (U.S.), Circ. 539, I, 31 (1953)	67.454	31	2	2	0	
	81.286	33	3	1	1	
Sys.: Cubic S.G.: Fm $\bar{3}m$ (225)	85.712	12	2	2	2	
a: 3.9231 b:	c: 103.508	6	4	0	0	
$\alpha$	$\beta$ :	$\gamma$ :	Z: 4	mp:		
Ref: Ibid.	117.711	22	3	3	1	
Dx: 21.461 Dm: 21.370 SS/FOM <sub>2</sub> = 143(0.0070, 9)	122.807	20	4	2	0	
	148.262	29	4	2	2	
Color: Light gray metallic Pattern taken at 26°C CAS #: 7440-06-4. Sample prepared at NBS, Gaithersburg, MD, USA, and estimated to be more than 99.99% pure. Opaque mineral optical data on specimen from unspecified locality: RR2Re=70.3, Disp.=16, VHN50=122-129, Color values---318, 324, 70.7. Ref: IMA Commission on Ore Microscopy QDF, Cu type, Gold group, gold subgroup. PSC: eF4. Mwt: 195.09. Volume[CD]: 60.38.						

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40-0932		Wavelength 1.5418			
Si		2θ	Int	h	k
Silicon		25.725	40	1	0 1
		33.205	100	2	0 1
		35.293	40	2	1 1
		36.010	40	3	0 0
Rad.: CuKα λ: 1.5418 Filter: Ni Beta M d-sp: Debye-Scherrer		43.619	80	3	2 0
Cut off:	Int. Estimation	51.828	50	3	3 0
	I/Icor.	57.490	20	3	3 1
Ref: Zhao, Y.-X et al., Solid State Commun., 59, 679 (1986)		68.429	10	5	1 1
Sys.: Tetragonal	S.G.: P422 (89)				
a: 7.482(5)	b: c: 3.856(5)	A: C: 0.5154			
α β γ		Z: 10.8 mp:			
Ref: Ibid.					

Dx: 2.333 Dm: SS/FOM g=2(.092, .39)

Rapid pressure release after being held at 12.0 GPa for one hour. Phase IX PSC tP10.80. Mwt: 28.09. Volume[CD]: 215.86.

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39-1425		Wavelength 1.5405981			
SiO2		2θ	Int	h	k
Silicon Oxide		21.985	100	1	0 1
		25.320	<1	1	1 0
		28.439*	8	1	1 1
		31.462*	9	1	0 2
Cristobalite, syn		36.080	13	2	0 0
Rad.: CuKα λ: 1.5405 Filter: Graph Monod-sp. Diffractometer		36.381*	4	1	1 2
Cut off: 17.7 Int. Diffract. I/Icor.		38.410	<1	2	0 1
Ref: Wong-Ng, W., McMurtrie, H., Paretzkin, B., Hubbard, C., Dragoo, A., NBS, Gaithersburg, MD, USA, ICDD Grant-in-Aid (1988)		42.656*	2	2	1 1
		44.843*	2	2	0 2
		47.063*	4	1	1 3
Sys.: Tetragonal	S.G.: P4 <sub>1</sub> 2 <sub>1</sub> 2 (92)	48.611*	4	2	1 2
a: 4.9732(4)	b: c: 6.9236(8)	A: C: 1.3922	51.940	<1	2 2 0
α β γ		Z: 4 mp:	52.869	<1	0 0 4
Ref: Wong-Ng, W et al., Powder Diffraction, 3, 253 (1988)		54.156*	2	2	0 3
		56.220	<1	1	0 4
		57.084*	3	3	0 1
Dx: 2.331 Dm: SS/FOM <sub>3</sub> (=84(0.0100, .36))		57.507*	1	2	1 3
Color: Colorless		58.680	<1	3	1 0
The temperature was - 25°C. Cristobalite was prepared by the Trans Tech Company using Berkeley 5 micron MIN-U-SIL(R). A two kilogram sample was heated at 1600°C for eight hours. The sample was then air quenched, treated with 6N HCl and then jet-milled. The +325 mesh fraction was then removed by sieving. There are a number of other forms of Si O <sub>2</sub> . The structure was determined by Peacock (1). O <sub>2</sub> Si type. Tungsten, fluorophlogopite used as an internal stands. PSC: tP12. To replace 11-695 and validated by calculated pattern. Mwt: 60.08. Volume[CD]: 171.24.		58.870	<1	2	2 2
		60.304*	2	3	1 1
		62.019*	2	3	0 2
		65.102*	2	3	1 2
		65.650*	1	2	0 4
		66.813*	1	2	2 3
		68.676*	2	2	1 4
		69.420	<1	3	2 1
		69.790	<1	3	0 3
		70.542*	1	1	0 5
		72.690*	1	3	1 3
		73.908*	1	3	2 2
		77.312	<1	2	2 4
		78.020	<1	4	0 1

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						Wavelength= 1.54056
			2θ	Int	h k l	
18-0979	PtTi3					
Platinum Titanium						
24.999	90	1	1	0		
35.655	45	2	0	0		
40.040	25	2	1	0		
44.028	100	2	1	1		
51.314	12	2	2	0		
57.913	16	3	1	0		
64.024	<1	2	2	2		
67.005*	4	3	2	0		
69.883	40	3	2	1		
75.506*	8	4	0	0		
80.996*	8	4	1	1		
86.394	10	4	2	0		
89.090*	4	4	2	1		
91.770	10	3	3	2		
97.161*	2	4	2	2		
102.585	8	5	1	0		
111.011	4	5	2	0		
113.934	12	5	2	1		
119.987	6	4	4	0		
126.367	6	5	3	0		
133.329	8	6	0	0		
137.171	<1	6	1	0		
141.295	16	6	1	1		
150.957	2	6	2	0		
Sys. Cubic		S.G.: Pm3n (223)				
a: 5.0327	b:	c:	A:	C:		
α	β	γ	Z: 2	mp		
Ref Ibid.						
Dx: 8.827	Dm:	SS/FOM <sub>2θ</sub> =72(.0123, 27)				
Color: Dark gray metallic						
Pattern at 25 °C. Sample prepared by R.M. Waterstrat by arc melting. Major impurities: 0.001-0.01% each of Al, Cr, Cu, and Si; 0.01-0.1% each of Fe and Pd. Cr3Si type. Tungsten used as an internal stand. PSC: cP8. To replace 18-979. Mwt: 338.79. Volume[CD]: 127.47.						

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						Wavelength= 1.54056
			2θ	Int	h k l	
17-0683	Pt <sub>2</sub> Si					
Platinum Silicide						
27.165*	2	1	0	1		
30.136	35	0	0	2		
32.124	90	1	1	0		
44.692	100	1	1	2		
45.740	35	2	0	0		
51.814*	2	1	0	3		
54.405*	2	2	1	1		
56.177	35	2	0	2		
62.726	10	0	0	4		
67.360	20	2	2	0		
71.777*	2	2	1	3		
72.286	25	1	1	4		
74.130*	2	3	0	1		
75.583	25	2	2	2		
76.661	25	3	1	0		
81.419	25	2	0	4		
Sys. Tetragonal		S.G.: I4/mmm (139)				
a: 3.933	b:	c: 5.910	A:	C: 1.5027		
α	β	γ	Z: 2	mp		
Ref Ibid.						
Dx: 15.195	Dm:	SS/FOM <sub>1θ</sub> =11(.091, 16)				

H<sub>2</sub> Th type. PSC: II6. Mwt: 418.27. Volume[CD]: 91.42.

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		Wavelength= 1.54056									
		2θ	Int	B	K	I	2θ	Int	B	K	I
34-0903	Pt12Si5	34.994	60	1	1	2	73.700	20	2	5	3
Platinum Silicide		37.425	100	2	3	1	75.197	60	3	7	0
		39.745	60	3	3	0	75.351	80	1	3	4
		42.000	100	4	2	0	78.255	100	7	1	2
Rad. CrKa	λ 2.2909	Filter:	d-sp	Debye-Scherrer							
Cut off	Int.	Estimation	I/Icor.								
Ref:	Ram, R., Bhan, Z. Metallkd., 69, 524 (1978)										
Sys.	Tetragonal	S.G.	I4/m (87)								
a:	9.607	b:	c: 5.542	A:	C: 0.5769						
α:		β:	γ:	Z: 2	mp:						
Ref:	Ibid										
Dx:	16.112	Dm:	SS/ROM <sub>2</sub> =5 (.085, .52)								
Omissions because of inadequate range of intensities.											
Pattern at 902°C. Stoichiometric elemental mixtures were melted in argon arc furnace, heat treated and quenched.											
Higher angle intensities enhanced by absorption. Ni12 P5 type. I <sub>SC</sub> d34. Mwt: 2481.51. Volume(CD): 511.50.											

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## ประวัติผู้เขียนวิทยานิพนธ์

นางสาวนิตยา แก้วเพชร เกิดวันที่ 27 พฤศจิกายน พ.ศ. 2541 ที่จังหวัดสงขลา สำเร็จการศึกษาปริญญาตรีวิทยาศาสตรบัญชิต ภาควิชาเคมี คณะวิทยาศาสตร์ มหาวิทยาลัยสงขลานครินทร์ เมื่อปีการศึกษา 2537 เน้นศึกษาต่อในหลักสูตรวิทยาศาสตรบัณฑิต สาขาเทคโนโลยีเคมี จุฬาลงกรณ์มหาวิทยาลัย ในปีการศึกษา 2542 สำเร็จในภาคการศึกษาต้น ปีการศึกษา 2545

